

## C-Band Booster Optical Amplifier Chip on Heatsink



**BOA1007H**

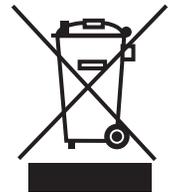
### Description

Thorlabs' BOA1007H is a high saturation output power, high bandwidth, polarization-maintaining Booster Optical Amplifier. The BOA1007H incorporates a highly efficient InP/InGaAsP Quantum Well (QW) layer structure and a reliable ridge waveguide design.

### Specifications

BOA1007H*				
	Symbol	Min	Typical	Max
Operating Current	$I_{OP}$	-	600 mA	750mA
Center Wavelength	$\lambda_C$	1530 nm	1550 nm	1570 nm
Optical 3 dB Bandwidth	BW	80 nm	85 nm	-
Saturation Output Power @ -3 dB	$P_{SAT}$	15 dBm	18 dBm	-
Small Signal Gain across BW @ $P_{IN} = -20$ dBm, $\lambda = 1550$ nm	G	26 dB	30 dB	-
Gain Ripple (RMS) @ $I_{op}$	$\delta G$	-	0.05 dB	0.2 dB
Polarization Extinction Ratio	PER	-	18 dB	-
Chip Noise Figure	NF	-	6.0 dB	8.0 dB
Forward Voltage	$V_F$	-	1.3 V	1.6 V
Chip Length	L	-	1.5 mm	-
Lateral Beam Exit Angle	$\theta_{EXT}$	-	19.5°	-
Beam Divergence Angle (FWHM)				
-Transverse	$\theta_T$	26°	34°	42°
-Lateral	$\theta_L$	10°	14°	30°

\* $T_{CHIP} = 25^\circ C$



### Performance Plots

